

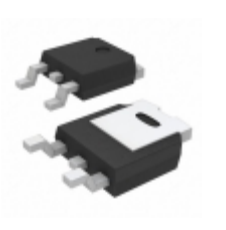

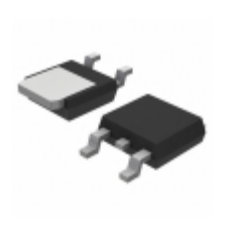





	<h2>STD26NF10</h2>
	<p>Hersteller-Teilenummer: STD26NF10</p> <p>Hersteller / Marke: STMicroelectronics</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 25A DPAK</p> <p>Datenblätter:  STD26NF10.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 56665 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD26NF10
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 100V 25A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	56665 pcs Stock
Serie	STripFET™ II
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	100W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	25A (Tc)
Rds On (Max) @ Id, Vgs	38 mOhm @ 12.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	55nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1550pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)























STD26NF10 ist neu im Original, Suche STD26NF10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD26NF10 STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD26NF10: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>STD25NF20 STMicroelectronics MOSFET N-CH 200V 18A DPAK</p>	 <p>STD25NF10LT4 STMicroelectronics MOSFET N-CH 100V 25A DPAK</p>	 <p>STD25P03LT4G AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V DPAK</p>	 <p>STD25NF10T4 STMicroelectronics MOSFET N-CH 100V 25A DPAK</p>
 <p>STD2640NL S STD2640NL S</p>	 <p>STD27GK08B Sirectifi IGBT Modules</p>	 <p>STD27GK08 SIRECTIFIER IGBT Modules</p>	 <p>STD27GK12 SIRECTIFIER IGBT Modules</p>

heiße Teile

Mehr

 STD20P07LT4G	 STD20P3H6AG	 STD222T4	 STD22NM20L	 STD22NM20N
 STD22NM20NT4	 STD22NM20T4	 STD253GK08	 STD253GK12	 STD253GK14
 STD253GK16	 STD253GK18	 STD2596-ADJ	 STD25N10F7	 STD25NE03
 STD25NE03LT4	 STD25NF06L	 STD25NF10	 STD25NF10L	 STD25NF10LA
 STD25NF10LT4	 STD25NF10T4	 STD25NF20	 STD25P03LT4G	 STD2640NL
 STD26NF10T4	 STD26P3LLH6	 STD27GK08	 STD27GK08B	 STD27GK12
 STD27GK12B	 STD27GK14	 STD27GK14B	 STD27GK16	 STD27GK16B
 STD27GK18	 STD27GK18B	 STD27N3LH5	 STD28P3LLH6AG	 STD29NF03L
 STD29NF03LT4	 STD2Hnk60Z	 STD2Hnk60Z-1	 STD2Hnk60Z-1SK	 STD2Hnk60ZT4
 STD2LN60K3	 STD2N52-1	 STD2N62K3	 STD2N95K5	 STD2NA50T4

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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